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CONTENTS

Classical semiconductors

AlGaN-based deep ultraviolet light-emitting diodes grown on nano-patterned sapphire substrates with significant improvement in internal quantum efficiency

P. Dong, J. Yan, Y. Zhang, J. Wang, J. Zeng, C. Geng, P. Cong, L. Sun, T. Wei, L. Zhao, Q. Yan, C. He, Z. Qin and J. Li

Impact of strained GaAs spacer between InP emitter and $\text{GaAs}_{1-y}\text{Sb}_y$ base on structural properties and electrical characteristics of MOCVD-grown InP/GaAs_{1-y}Sb_y/InP DHBTs

T. Hoshi, N. Kashio, H. Sugiyama, H. Yokoyama, K. Kurishima, M. Ida, H. Matsuzaki and M. Kohtoku

31

Thickness influence of thermal oxide layers on the formation of self-catalyzed InAs nanowires on Si(111) by MOCVD

X. Wang, X. Yang, W. Du, H. Ji, S. Luo and T. Yang

Self-limiting growth when using trimethyl bismuth (TMBi) in the metal-organic vapor phase epitaxy (MOVPE) of $\text{GaAs}_{1-y}\text{Bi}_y$

K. Forghani, Y. Guan, A.W. Wood, A. Anand, S.E. Babcock, L.J. Mawst and T.F. Kuech

38

Preferred grain orientations in silicon ribbons grown by the string ribbon and the edge-defined film-fed growth methods

L. Stockmeier, G. Müller, A. Seidl, T. Lehmann, C. Reimann and J. Friedrich

Vertical Bridgman growth of sapphire—Seed crystal shapes and seeding characteristics

K. Hoshikawa, J. Osada, Y. Saitou, E. Ohba, C. Miyagawa, T. Kobayashi, J. Yanagisawa, M. Shinozuka and K. Kanno

80

Czochralski growth of heavily tin-doped Si crystals

I. Yonenaga, T. Taishi, K. Inoue, R. Gotoh, K. Kutsukake, Y. Tokumoto and Y. Ohno

Solution growth; industrial biological and molecular crystallization

InN growth on BaTiO₃ (111) substrates: A first-principles study

J. Wang, G. Tang, L. Pu and X.S. Wu

Top-seeded solution growth of three-inch-diameter 4H-SiC using convection control technique

K. Kusunoki, N. Okada, K. Kamei, K. Moriguchi, H. Daikoku, M. Kado, H. Sakamoto, T. Bessho and T. Ujihara

68

Polytype transformation and structural characteristics of 3C-SiC on 6H-SiC substrates

R. Vasiliauskas, M. Marinova, M. Syväjärvi, E.K. Polychroniadis and R. Yakimova

Influence of the spin-orientation of free and unpaired protons of ortho-water on the crystallization of the (001) face of TGS crystal: "in situ" investigation

A.Z. Bikov, R.V. Genova and N.G. Vassilev

90

Electronic materials

Crystal growth and properties of the non-centrosymmetric superconductor, Ru₂B₃

R.P. Singh, N.A. Parzyk, M.R. Lees, D.McK. Paul and G. Balakrishnan

Synthesis of sodium caseinate–calcium carbonate microspheres and their mineralization to bone-like apatite

Z. Xu, G. Liang, L. Jin, Z. Wang, C. Xing, Q. Jiang and Z. Zhang

116

Analysis of the VIS–NIR spectral reflectance of Bi/GaAs structures grown by MOVPE and UHVE

M.M. Habchi, I. Massoudi, A. Rebey, R. Ben Chaâbane and B. El Jani

Comparative in vitro studies on disodium EDTA effect with and without *Proteus mirabilis* on the crystallization of carbonate apatite and struvite

J. Prywer, M. Olszynski, A. Torzewska and E. Miśniczek-Brzóska

123

Contents continued on inside back cover



Contents continued from outside back cover

General subjects

Spontaneous growth of diamond from MnNi solvent-catalyst using opposed anvil-type high-pressure apparatus
N.D. Zhigadlo

Growth and analysis of modulation-doped AlGaN/GaN heterostructure on semi-insulating SiC substrate
D.-S. Kim, C.-H. Won, R.-H. Kim, B.-O. Lim, G.-W. Choi, B.-H. Lee, H.-J. Kim, I.-P. Hong and J.-H. Lee

Characterizations of ZnO and $Zn_{(1-x)}Cd_xO$ thin films grown on Zn- and O-face ZnO substrates by metal organic chemical vapor deposition
M.A. Boukadhaba, A. Fouzri, C. Saidi, N. Sakly, A. Souissi, A. Bchetnia, C. Sartel, V. Sallet and M. Oumezzine

1	An analytical model for solute diffusion in multicomponent alloy solidification S.L. Sobolev, L.V. Poluyanov and F. Liu	46
5	Growth of ultra-long sodium tungsten oxide and tungsten oxide nanowires: Effects of impurity and residue deposition T. Sheng, P.P. Chavvakula, B. Cao, N. Yue, Y. Zhang and H. Zhang	61
14	Growth and magneto-optical characteristic of $Ho_2Ti_2O_7$ crystal J. Kang, W. Zhang, W. Xu, X. Chen, W. Liu, F. Guo, S. Wu and J. Chen	104